NSN 5962-01-105-1325

Memory Microcircuit - Page 1 of 2

AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-105-1325

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inch	es and 0.310 inches
Body Height:	
Between 0.140 inch	es and 0.185 inches
Maximum Power D	ssipation Rating:
715.0 milliwatts	
Operating Tempura	ture Range:
-55.0/+125.0 degree	s celsius
Storage Tempuratu	re Range:
-65.0/+150.0 degree	s celsius
End Application:	
Radar set, type an/f	ps-115
Features Provided:	
Hermetically sealed	and monolithic and positive outputs and negative outputs and 3-state output and w/enable and w/buffered output and
w/decoded output a	id programmable
Inclosure Material:	
Ceramic and glass	
Inclosure Configur	ation:
Dual-in-line	
Output Logic Form	
Transistor-transistor	logic
Input Circuit Patter	n:
10 input	
Case Outline Source	e And Designator:
D-2 mil-m-38510	
Terminal Surface T	reatment:
Solder	
Voltage Rating And	Type Per Characteristic:
5.5 volts power sou	ce
Time Rating Per Ch	acteristic:
85.00 nanoseconds	propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	be:
Rom	
Memory Capacity:	
Unknown	
Test Data Docume	it:
49956-952369 draw	ng (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specifi	cation, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And	Quantity:
16 printed circuit	

16 printed circuit

Shelf Life:

NSN 5962-01-105-1325

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

A458a0

